

**PROTECTION PRODUCTS - MicroClamp™**
**Description**

The μClamp™ series of TVS arrays are designed to protect sensitive electronics from damage or latch-up due to ESD. It is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDAs. It features large cross-sectional area junctions for conducting high transient currents. It offers superior electrical characteristics such as lower clamping voltage and no device degradation when compared to MLVs. They offer desirable characteristics for board level protection including fast response time, low operating and clamping voltage, and no device degradation.

The μClamp™1201P is in a 2-pin, RoHS/WEEE compliant, SLP1006P2 package. It measures 1.0 x 0.6 x 0.50mm. The leads are spaced at a pitch of 0.65mm and are finished with lead-free NiPdAu. Each device will protect one line operating at 12 volts. It gives the designer the flexibility to protect single lines in applications where arrays are not practical. They may be used to meet the ESD immunity requirements of IEC 61000-4-2, Level 4 (±15kV air, ±8kV contact discharge). The combination of small size and high ESD surge capability makes them ideal for use in portable applications such as cellular phones, digital cameras, and MP3 players.

**Features**

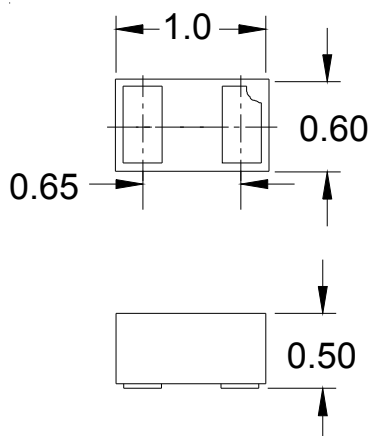
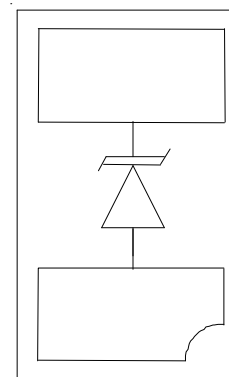
- ◆ Transient protection for data lines to **IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact) IEC 61000-4-4 (EFT) 40A (tp = 5/50ns) Cable Discharge Event (CDE)**
- ◆ Ultra-small package (1.0 x 0.6 x 0.5mm)
- ◆ Protects one I/O or power line
- ◆ Low clamping voltage
- ◆ Working voltage: 12V
- ◆ Low leakage current
- ◆ Solid-state silicon-avalanche technology

**Mechanical Characteristics**

- ◆ SLP1006P2 package
- ◆ RoHS/WEEE Compliant
- ◆ Nominal Dimensions: 1.0 x 0.6 x 0.50 mm
- ◆ Lead Finish: NiPdAu
- ◆ Molding compound flammability rating: UL 94V-0
- ◆ Marking: Marking code, cathode band
- ◆ Packaging: Tape and Reel

**Applications**

- ◆ Cellular Handsets & Accessories
- ◆ Personal Digital Assistants (PDAs)
- ◆ Notebooks & Handhelds
- ◆ Portable Instrumentation
- ◆ Digital Cameras
- ◆ Peripherals
- ◆ MP3 Players

**Dimensions**

**Nominal Dimensions (mm)**
**Schematic & PIN Configuration**

**SLP1006P2 (Bottom View)**

**PROTECTION PRODUCTS**
**Absolute Maximum Rating**

Rating	Symbol	Value	Units
Peak Pulse Power (tp = 8/20μs)	$P_{pk}$	200	Watts
Maximum Peak Pulse Current (tp = 8/20μs)	$I_{pp}$	8	Amps
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	$V_{pp}$	+/- 20 +/- 15	kV
Operating Temperature	$T_J$	-55 to +125	°C
Storage Temperature	$T_{STG}$	-55 to +150	°C

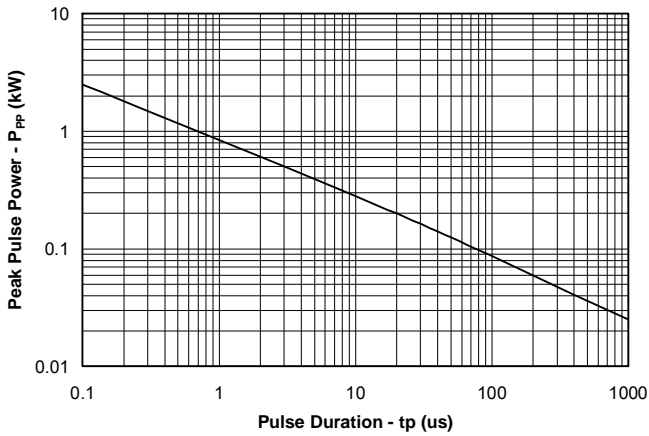
**Electrical Characteristics (T=25°C)**

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	$V_{RWM}$				12	V
Reverse Breakdown Voltage	$V_{BR}$	$I_t = 1mA$	13.3	15.5	17.5	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 12V, T=25°C$		0.100	1	μA
Forward Voltage	$V_F$	$I_F = 10mA$		0.8		V
Clamping Voltage	$V_C$	$I_{pp} = 1A, t_d = 8/20μs$			19	V
Clamping Voltage	$V_C$	$I_{pp} = 8A, t_d = 8/20μs$			25	V
Junction Capacitance	$C_J$	$V_R = 0V, f = 1MHz$			60	pF

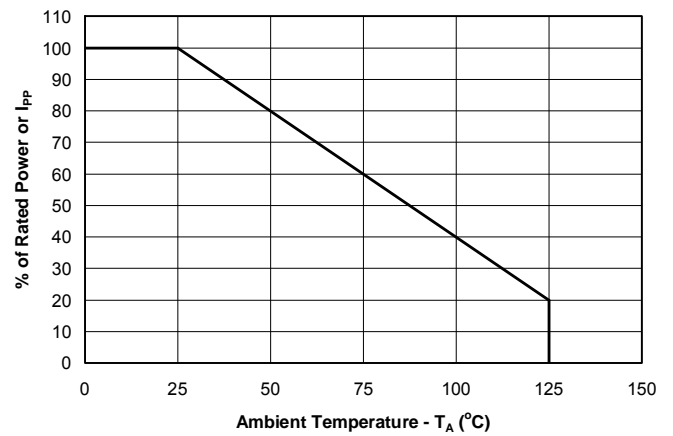
## PROTECTION PRODUCTS

### Typical Characteristics

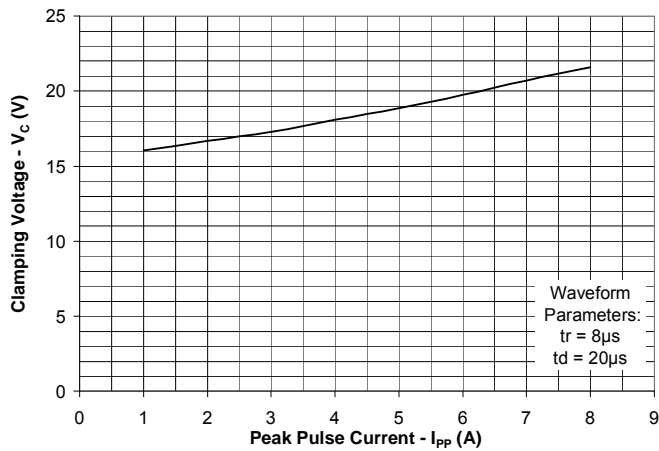
#### Non-Repetitive Peak Pulse Power vs. Pulse Time



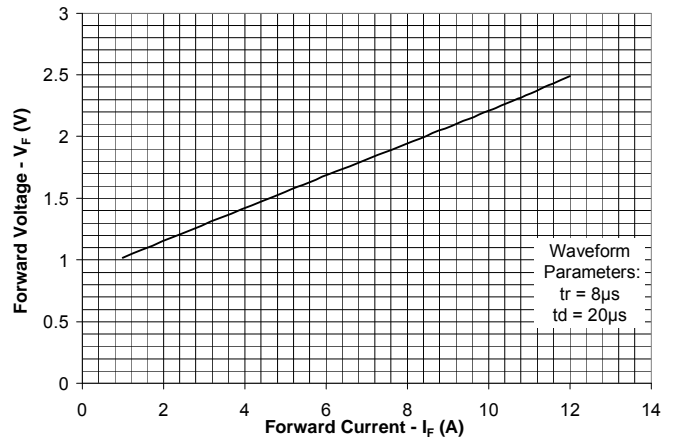
#### Power Derating Curve



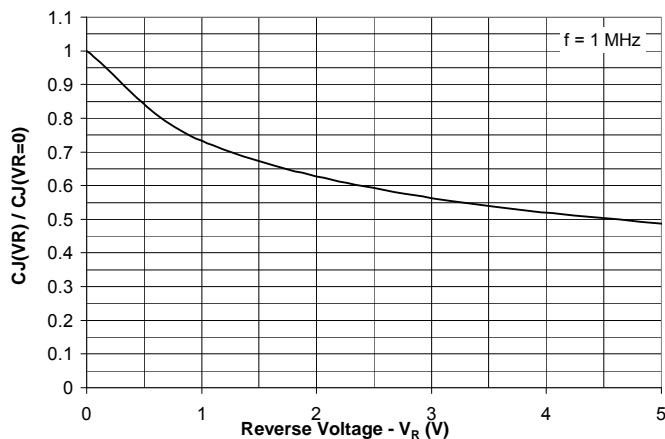
#### Clamping Voltage vs. Peak Pulse Current



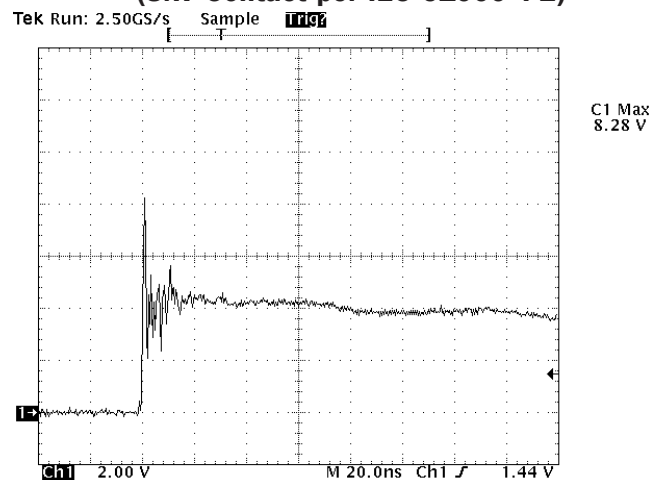
#### Forward Voltage vs. Forward Current



#### Normalized Junction Capacitance vs. Reverse Voltage



#### ESD Clamping (8kV Contact per IEC 61000-4-2)



Note: Data is taken with a 10x attenuator

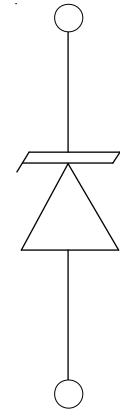
**PROTECTION PRODUCTS****Applications Information****Device Connection Options**

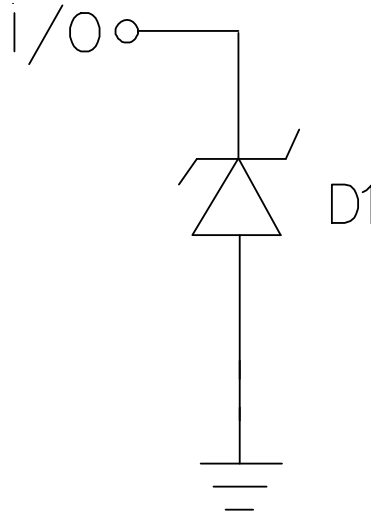
These TVS diodes are designed to protect one data, I/O, or power supply line. The device is unidirectional and may be used on lines where the signal polarity is above ground. The cathode band should be placed towards the line that is to be protected.

**Circuit Board Layout Recommendations for Suppression of ESD.**

Good circuit board layout is critical for the suppression of ESD induced transients. The following guidelines are recommended:

- Place the TVS near the input terminals or connectors to restrict transient coupling.
- Minimize the path length between the TVS and the protected line.
- Minimize all conductive loops including power and ground loops.
- The ESD transient return path to ground should be kept as short as possible.
- Never run critical signals near board edges.
- Use ground planes whenever possible.

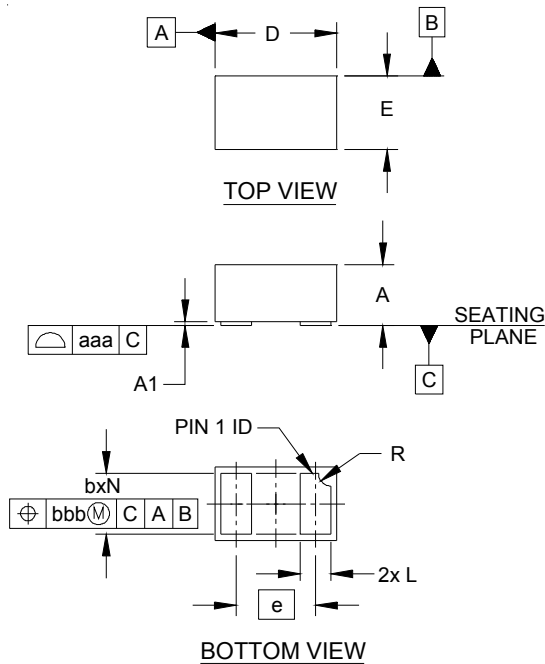
**Circuit Diagram**

**PROTECTION PRODUCTS**
**Applications Information - Spice Model**

**uClamp1201P Spice Model**

<b>uClamp1201P Spice Parameters</b>		
<b>Parameter</b>	<b>Unit</b>	<b>D1 (TVS)</b>
IS	Amp	1.48E-14
BV	Volt	15.33
VJ	Volt	0.723
RS	Ohm	0.772
IBV	Amp	1.0E-3
CJO	Farad	52E-12
TT	sec	2.541E-9
M	--	0.268
N	--	1.1
EG	eV	1.11

PROTECTION PRODUCTS

Outline Drawing - SLP1006P2

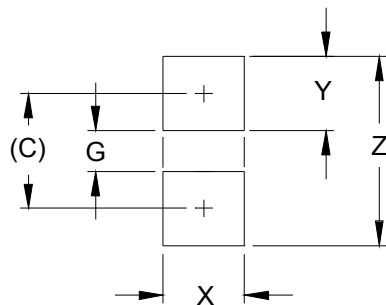


DIM	DIMENSIONS					
	INCHES			MILLIMETERS		
	MIN	NOM	MAX	MIN	NOM	MAX
A	.016	.020	.022	0.40	0.50	0.55
A1	.000	.001	.002	0.00	0.03	0.05
b	.018	.020	.022	0.45	0.50	0.55
D	.035	.039	.043	0.90	1.00	1.10
E	.020	.024	.028	0.50	0.60	0.70
e	.026 BSC			0.65 BSC		
L	.008	.010	.012	0.20	0.25	0.30
R	.002	.004	.006	0.05	0.10	0.15
N	2			2		
aaa	.003			0.08		
bbb	.004			0.10		

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).

Land Pattern - SLP1006P2



DIM	DIMENSIONS	
	INCHES	MILLIMETERS
C	(.033)	(0.85)
G	.012	0.30
X	.024	0.60
Y	.022	0.55
Z	.055	1.40

NOTES:

1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY. CONSULT YOUR MANUFACTURING GROUP TO ENSURE YOUR COMPANY'S MANUFACTURING GUIDELINES ARE MET.